EECE488 Analog CMOS Integrated Circuit Design Assignment 2 Due: Thursday February 24th, 2011 at 9:30am

1. a) Use HSPICE and the 0.35 μ m CMOS technology library used in our class to plot I_D versus V_{DS} of an NMOS transistor with W=7 μ m and L=0.35 μ m when its V_{GS} is 1V or 2V. For each V_{GS} use two difference V_{BS} of 0V and -1V.

b) Assuming that long channel quadratic equations for I_D holds, use the information from the I_D plots in part (a) to calculate a rough estimate of the process parameters V_{th0} , $\mu_n C_{ox}$, γ and λ for the transistor you used in part (a).

c) For $V_{BS}=0$, calculate g_m of the transistor in part (a) for each value of V_{GS} based on your estimated process parameters in part b and long channel equations discussed in class. Compare the estimated g_m values with those calculated by HSPICE (using gmo) and calculate the relative error.

2. Design a common-source amplifier with a resistive load based on the schematic shown below with the following design specifications:

- Transistor M1 is in saturation
- The minimum possible output voltage to keep M1 in saturation is 0.2V
- Total power consumption of the amplifier is 3mW
- Absolute value of gain of 15
- L=0.5µm for the transistor

The technology parameters are:

 λ (NMOS) = 0, γ = 0, V_{DD} =3V, V_{TH} (NMOS) = 0.5V, $\mu_n C_{ox}$ =1 mA/V²



Find the following values:

a) DC level of the input,

b) width (W_1) of transistor M_1 ,

c) R_D,

d) nominal dc level (bias level) of the output node, and

e) Maximum output signal swing for a symmetric output signal.

3. In the following circuit, assuming that the transistor is operating in the saturation region:

a) Find the required V_{bias} for which the dc value of the V_{out} is 1.44V.

b) Is the assumption that the transistor is in the saturation region correct?

c) Find the small-signal gain V_{out}/V_{sig} .

Assume $\lambda = 0$, $\gamma = 1V^{1/2}$, $2\Phi_F = 0.64V$, $V_{TH0} = 0.4V$, $\mu_n C_{ox} = 800 \ \mu A/V^2$, $(W/L)_{NMOS} = 20$, $R_D = R_S = 0.5k\Omega$, and $V_{DD} = 1.8V$.



4. Calculate the gain of the following circuit at very low and very high frequencies. Neglect all other capacitances that are not shown in the circuit and assume $\lambda = \gamma = 0$.



Good luck!